

# Monte Carlo simulation of polarization switching and electrocaloric effect in ferroelectrics with random fields



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## Motivation

- *Electrocaloric effect* (ECE) has high application potential for solid refrigeration.
- Some *relaxor ferroelectrics* (RFEs) can produce higher ECE at lower electric field.
- Origins of RFEs and ECE are still under debate, and are deserved to be studied and optimized.

## Lattice based model

Lattice based model is utilized for calculation with periodic boundary condition. Lattice constant  $a_0 = 4\text{\AA}$ , and thus the volume of unit cell  $V_0 = a_0^3$ .

## Total energy

$$H^* = H_D + H_{dip} + H_{gr} + H_e + U$$

Landau multi-well potential:

$$H_D = V_0 \sum_i \left[ -\frac{a}{2}(P_x^2(\mathbf{r}_i) + P_y^2(\mathbf{r}_i)) + \frac{b}{4}(P_x^4(\mathbf{r}_i) + P_y^4(\mathbf{r}_i)) \right]$$

where  $a = 13.7128 \times 10^8 \text{ J m C}^{-2}$ ,  $b = 28.908 \times 10^9 \text{ J m}^5 \text{ C}^{-4}$ ,  $\mathbf{r}_i$  is the coordinate of site  $i$ .

Dipole-dipole interaction energy:

$$H_{dip} = S_A V_0^2 \frac{1}{8\pi\epsilon_0\epsilon_r} \sum_{[i,j]} \left[ \frac{\mathbf{P}(\mathbf{r}_i) \cdot \mathbf{P}(\mathbf{r}_j)}{|\mathbf{r}_{ij}|^3} - \frac{3[\mathbf{P}(\mathbf{r}_i) \cdot \mathbf{r}_{ij}][\mathbf{P}(\mathbf{r}_j) \cdot \mathbf{r}_{ij}]}{|\mathbf{r}_{ij}|^5} \right]$$

where  $\epsilon_r = 12$  is the relative permittivity at high frequency and the cut-off radius is eight times the lattice constant.

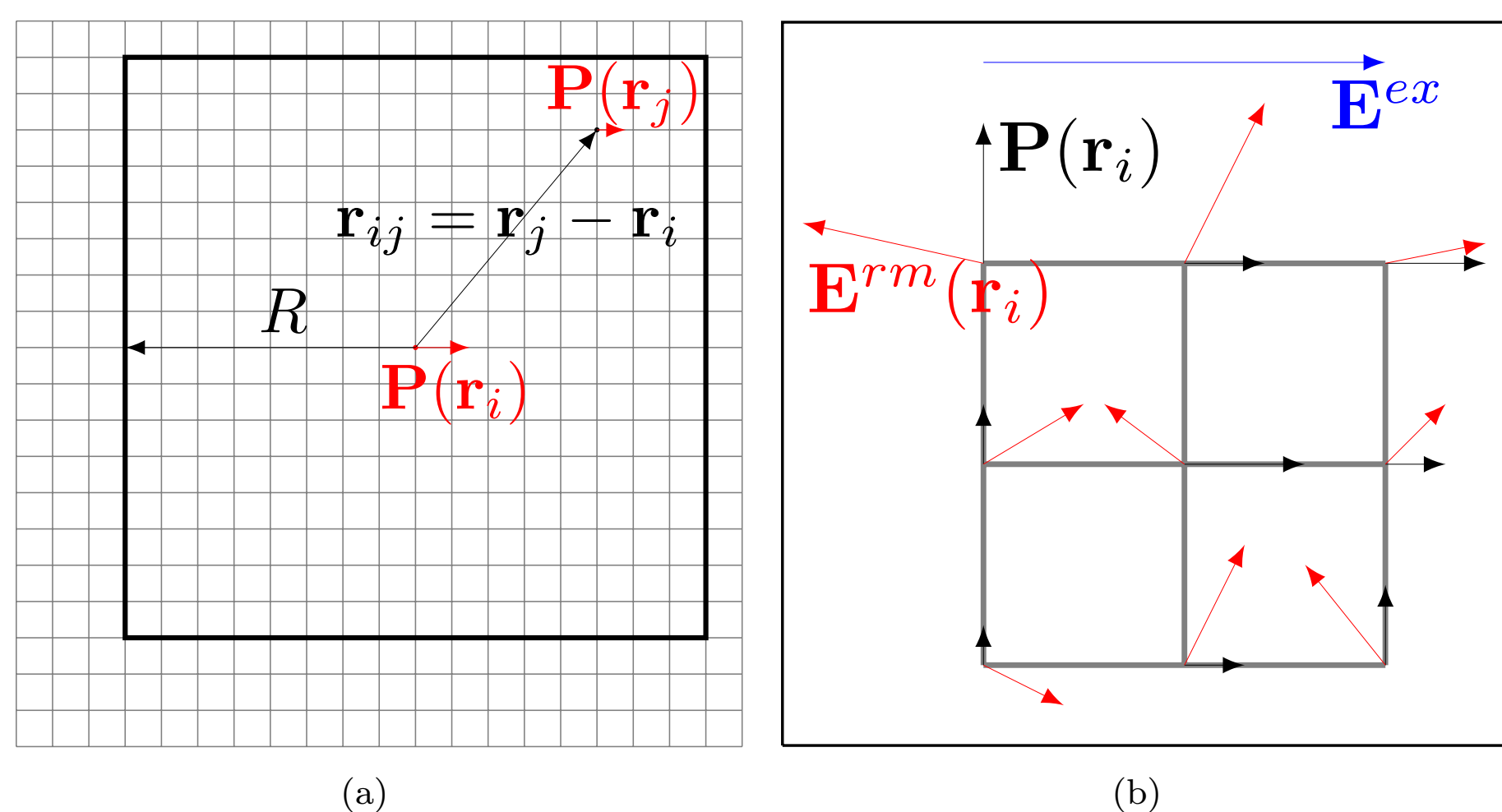


FIGURE 1: Illustration for (a) dipole-dipole interaction and (b) electrostatic energy.

Gradient energy:

$$H_{gr} = S_J V_0 \sum_i \left[ g_1(P_{x,x}^2(\mathbf{r}_i) + P_{y,y}^2(\mathbf{r}_i)) + g'_1 P_{x,x}(\mathbf{r}_i) P_{y,y}(\mathbf{r}_i) + g_2(P_{x,y}(\mathbf{r}_i) + P_{y,x}(\mathbf{r}_i))^2 + g'_2(P_{x,y}(\mathbf{r}_i) - P_{y,x}(\mathbf{r}_i))^2 \right]$$

where  $P_{i,j} = \partial P_i / \partial x_j$  and  $g_1 = g'_1 = g_2 = g'_2 = 2 \times 10^{-11} \text{ J m}^3 \text{ C}^{-2}$ .

Electrostatic energy:

$$H_e = -V_0 \sum_i \left[ \mathbf{P}(\mathbf{r}_i) \cdot (\mathbf{E}^{ex} + \mathbf{E}^{rm}(\mathbf{r}_i)) \right]$$

where  $\mathbf{E}^{ex}$  is the external electric field,  $\mathbf{E}^{rm}(\mathbf{r}_i)$  is the random field[1] at site  $i$ .

Thermal energy:

$$U = \frac{f}{2} N k_B T$$

where  $f$  is the number of degrees of freedom per unit cell,  $N$  is the number of sites.

## Simulation algorithm

Canonical Monte Carlo:  $T = \text{constant}$ .

$$p(\mathbf{r}_i) = \min \left[ 1, \exp \left( -\frac{\Delta H(\mathbf{r}_i)}{k_B T} \right) \right]$$

where  $\Delta H(\mathbf{r}_i)$  denotes the change in the potential energy of the system. The switching is approved if the switching probability  $p(\mathbf{r}_i)$  for site  $i$  is not less than a randomly generated number  $Rnd$  within  $[0, 1]$ .

Microcanonical Monte Carlo[2]:  $H = \text{constant}$ .

$$\sum_{i,k} Demon(\mathbf{r}_i, k) = \frac{f}{2} N k_B T$$

where  $Demon(\mathbf{r}_i, k)$  is the thermal energy at site  $i$  for the  $k$ -th demon. If  $\Delta H(\mathbf{r}_i)$  is not less than  $Demon(\mathbf{r}_i, k)$ , the switching is approved, and  $Demon(\mathbf{r}_i, k) = Demon(\mathbf{r}_i, k) - \Delta H(\mathbf{r}_i)$ .

## Results

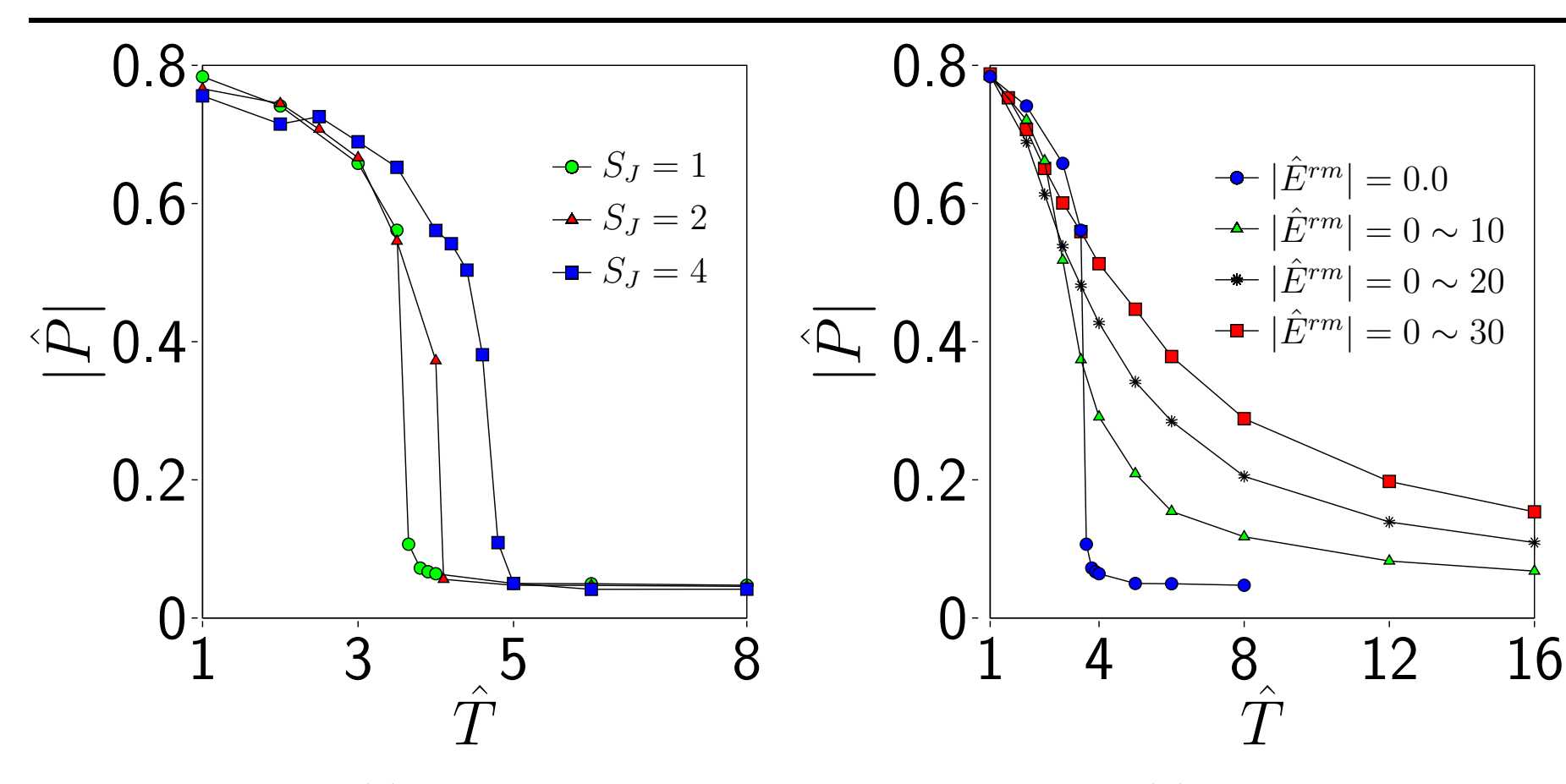


FIGURE 2: Temperature dependence of polarization for (a) ferroelectrics (FEs) with  $S_A = 1$ ,  $|\hat{E}^{rm}| = 0$  and (b) RFEs with  $S_A = 1$ ,  $S_J = 1$ .  $T = T_0 \hat{T}$ ,  $T_0 = 100 \text{ K}$ ;  $P = P_0 \hat{P}$ ,  $P_0 = 0.46 \text{ C m}^{-2}$ .

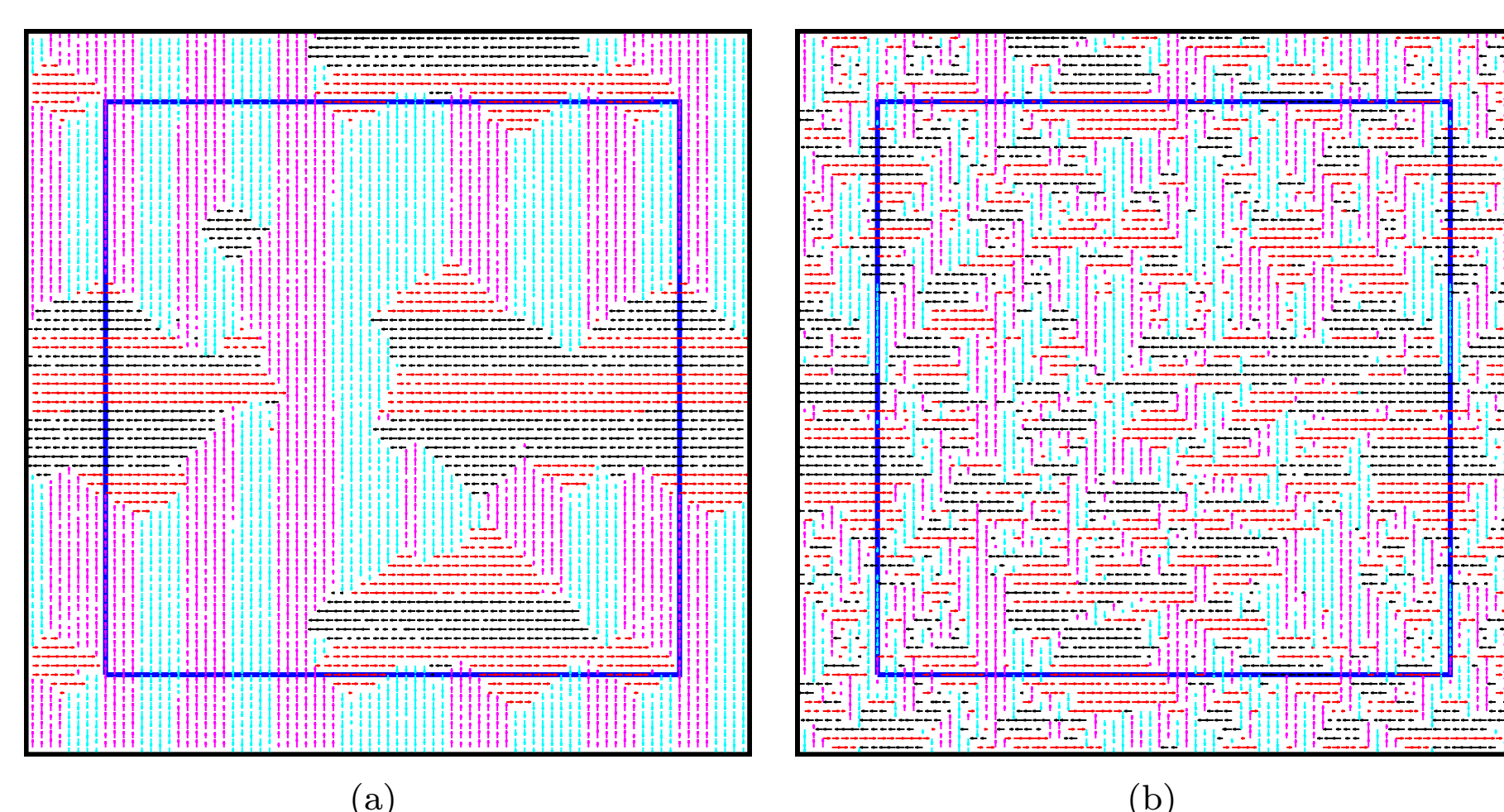


FIGURE 3: When  $S_A = 1$ ,  $S_J = 1$ ,  $\hat{T} = 2$  domain configurations are illustrated for (a) FEs and (b) RFEs with  $|\hat{E}^{rm}| = 20$ .  $E = E_0 \hat{E}$ ,  $E_0 = 4.6875 \times 10^7 \text{ V m}^{-1}$ .

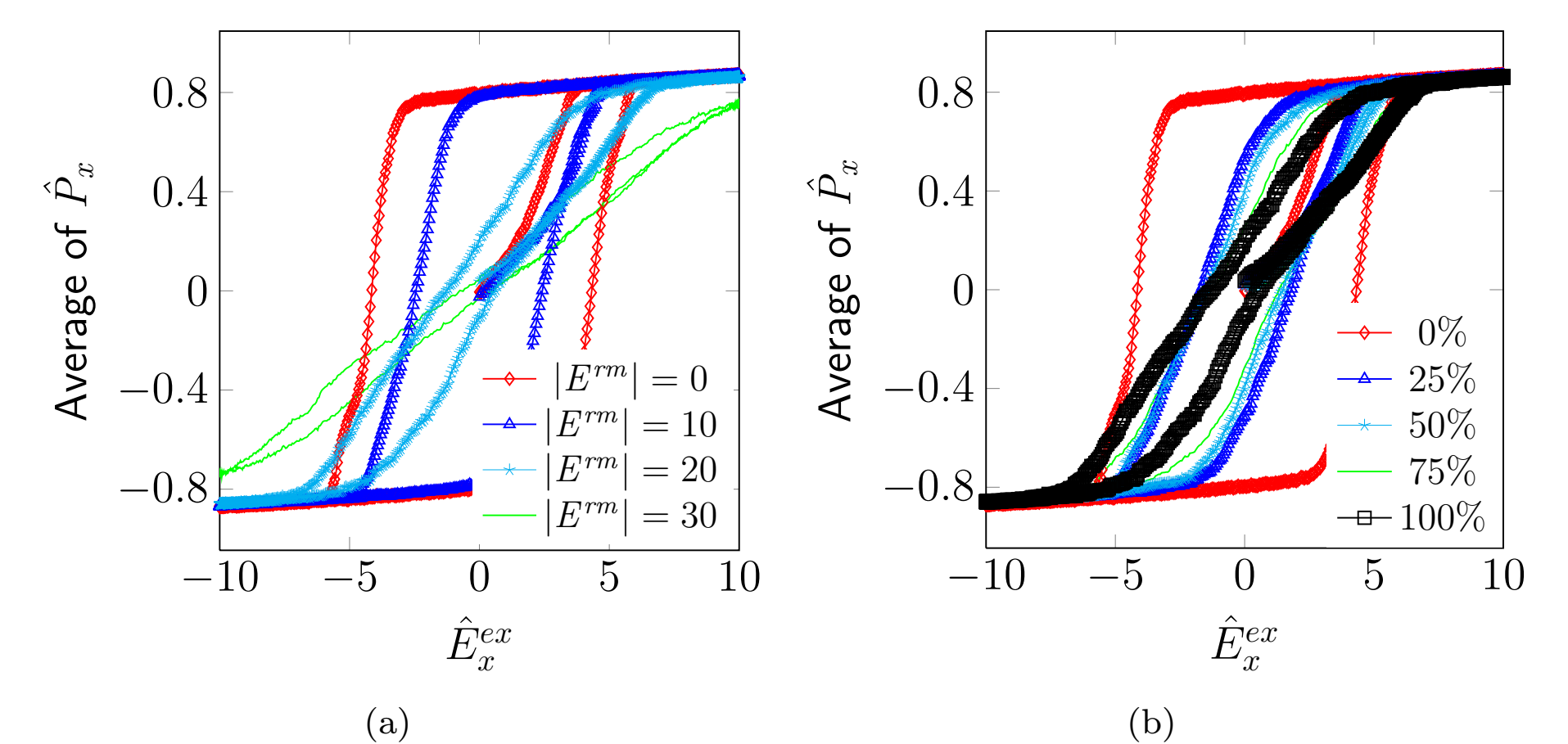


FIGURE 4: Hysteresis of (a) FEs and RFEs with  $S_J = 1$ ,  $S_A = 1$ ,  $\hat{T} = 2$  and (b) RFEs with  $|\hat{E}^{rm}| = 20$  for different proportions of sites with random fields.

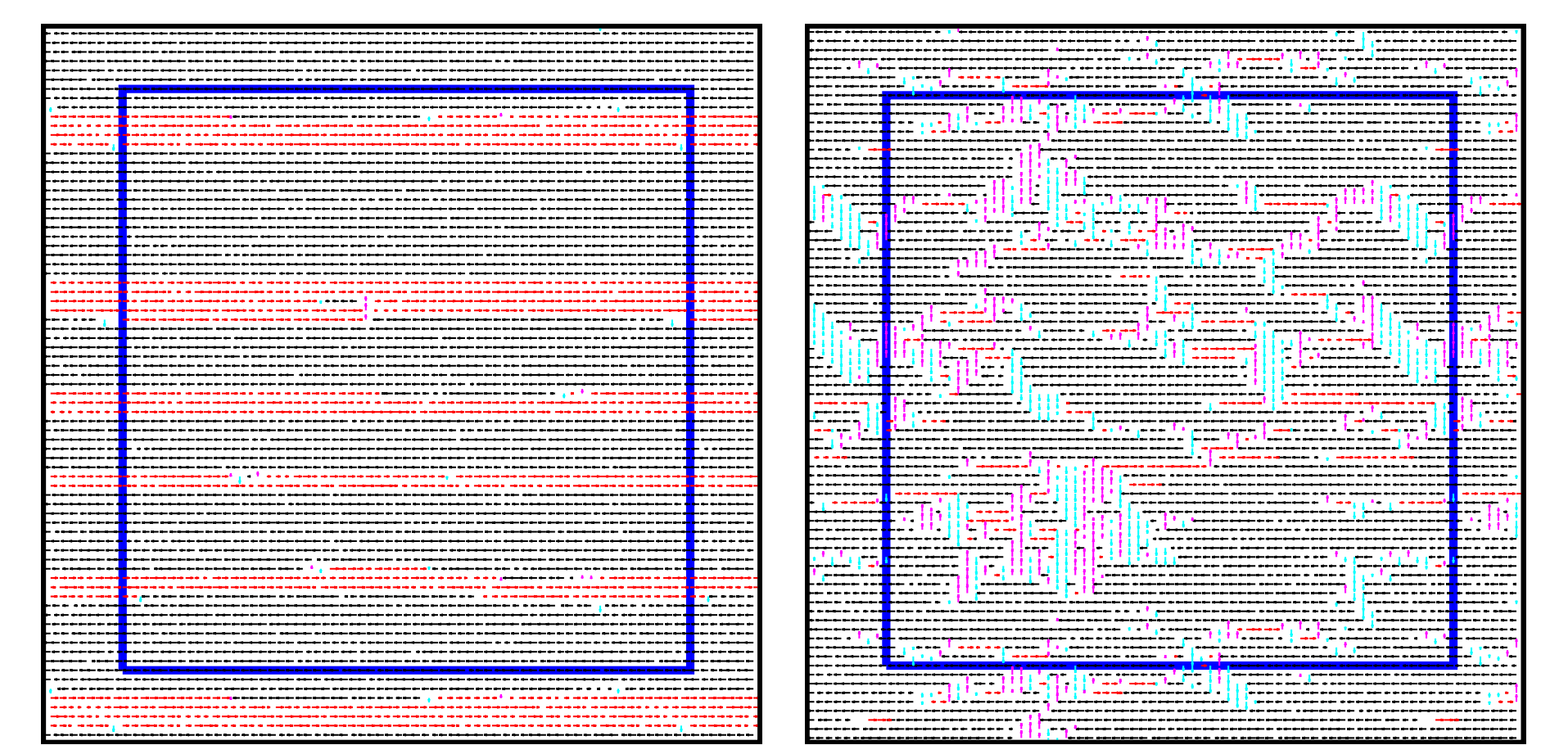


FIGURE 5: Snapshots of the domain structure at  $\hat{E}_x^{ex} = -4.76$  for (a) FEs and (b) RFEs with  $|\hat{E}^{rm}| = 20$ .

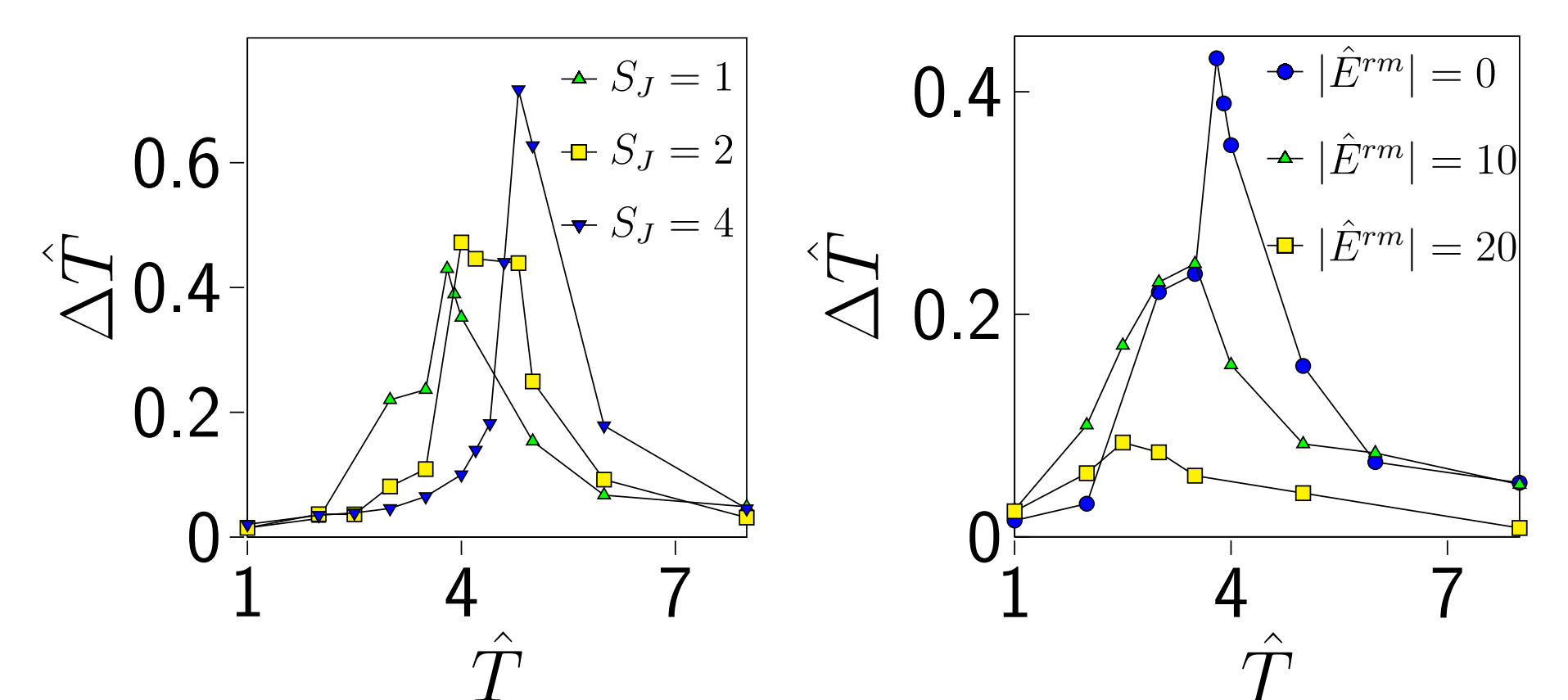


FIGURE 6: ECE for (a) FEs with  $|\hat{E}^{rm}| = 0, 10, 20$  and (b) RFEs with  $S_A = 1$ ,  $S_J = 1$ ,  $\hat{E}_x^{ex} = 2$ .

## Conclusions

- Higher gradient energy leads to higher phase transition temperature. Static random fields result in a wide phase transition range.
- Domain miniaturization and decrease of remnant polarization are observed when random fields are present.
- The magnitude of random fields determines the decrease in the saturation polarization, while the number of random fields is responsible for the decrease of the remnant polarization.
- Gradient energy and dipole interaction promote ECE effect. Higher gradient energy shifts the ECE peak to higher temperature.
- When the random field is stronger, the ECE effect becomes weaker, but the ECE peak is shifted to a lower temperature.

## Acknowledgements

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## References

- [1] V. Westphal, W. Kleemann, and M. D. Glinchuk. Diffuse phase transitions and random-field-induced domain states of the "relaxor" ferroelectric  $\text{pbm}_{1/3}\text{nb}_{2/3}\text{o}_3$ . *Phys. Rev. Lett.*, 68:847–850, Feb 1992.
- [2] I. Ponomareva and S. Lisenkov. Bridging the macroscopic and atomistic descriptions of the electrocaloric effect. *Phys. Rev. Lett.*, 108:167604, 2012.